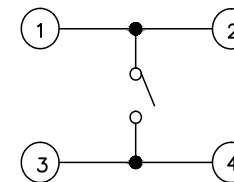
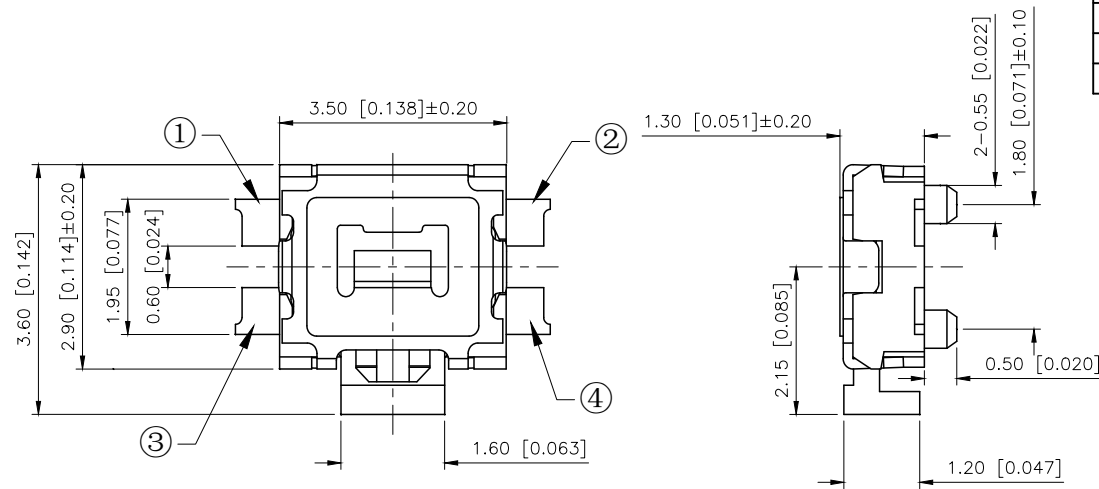


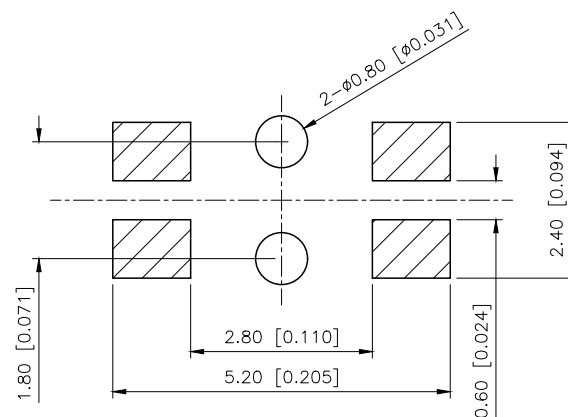
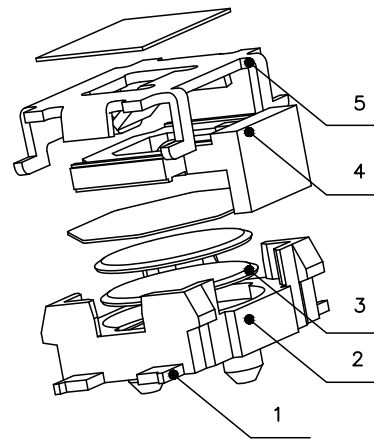
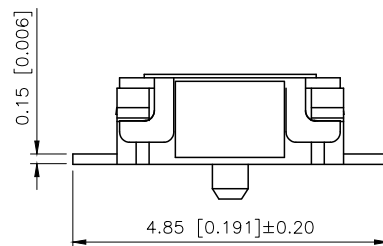
	REVISIONS				
REV.	ECN NO.	LOCATION	DESCRIPTION	DATE	DESIGN
A0	N/A		INITIAL RELEASE	/	/
A1	N/A		图面升级整理图面	2025.06.06	阿树



CIRCUIT DIAGRAM

SPECIFICATION

Contact Rating:	50mA,12V DC
Contact Resistance:	100mΩ max
Insulation Resistance:	100MΩ min.500V DC
Dielectric Strength:	250V AC/1minute
Operating Temp:	-30℃~+85℃
Storage Temp:	-30℃~+80℃
Operating Temp:	100,000cycles



P.C.B LAYOUT

PAPT NO	TS-1186F-X-X
Operating Force	B:160gf C:260gf
Height	H:3.6
Fixed column	A:With B:Without

⑤	Cover	1	SUS	
④	Keystone	1	Pa46	Black
③	Contact	1	F.ag/Sus	
②	Housing	1	LCP	Black
①	Terminal	1	Brass (0.30t)	Plating silvering
ITEM	PAPT NAMF	QTY	MATERIAL	FINISHING

AuGLAR	$\pm 5^\circ$
X.	± 0.40
X.x	± 0.30
X.xx	± 0.20
X.xxx	± 0.15
UNSPECIFIED TOLERANCES	

XKB 星城 Connection

DESIGN	阿树	VIEW: 	MODEL TYPE: TACT SWITCH
CHECKED		UNIT: mm/in	PART NO.: TS-1186F-X-X
APPROVED		SIZE: A4	DWG NO.:

SCALE	PAGE	REVISION
N/A	1/1	A1